# DESCRIPTION

The fundamental of SP6019D synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing to control the SR in present cycle by "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. SP6019D is specially suitable for Forward and DC/DC Module.

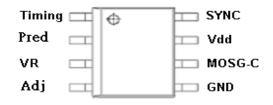
# FEATURES

- Offers efficiency improvement over Schottky Diode (depends on drive configuration of the SR).
- Drives all Power MOSFET.
- Prediction gate timing control.
- Minimum MOSFET body diode conduction.
- Operating at high switching frequency.
- Synchronize to transformer secondary voltage waveform.
- Linear setting of timing function.
- SOP-8 Package

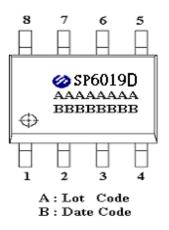
### APPLICATION

- Servers & workstations
- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- DC/DC Power Module

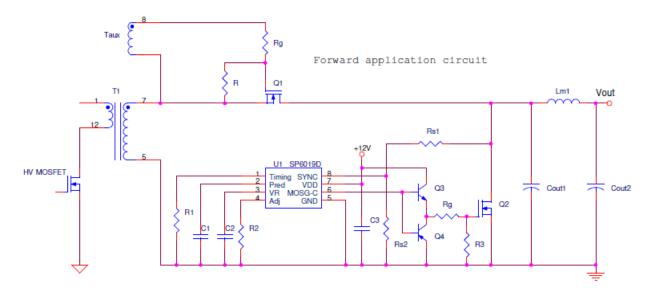
#### **PIN CONFIGURATION (SOP-8)**



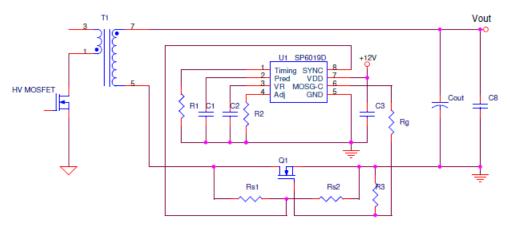
# PART MARKING



# **TYPICAL APPLCATION CIRCUIT**



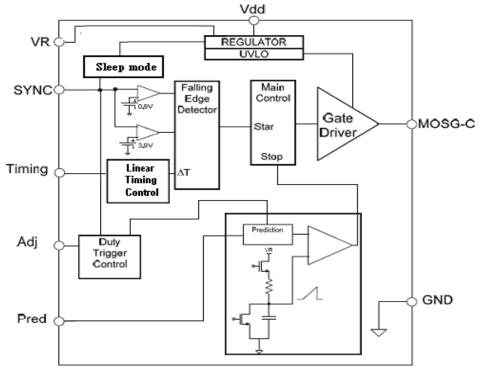
Fly-back application circuit



#### **PIN DESCRIPTION**

Pin	Symbol	Description
1	Timing	Discontinuous current filter timing adjustment resistor connection.
2	Pred	Capacitor to store previous cycle timing for SR MOSFET.
3	VR	Voltage Regulator.
4	Adj	Trigger point adjustment for Dynamic state.
5	GND	Ground connection.
6	MOSG-C	Catch MOSFET gate drive.
7	Vdd	DC supply voltage.
8	SYNC	Synchronized signal from the V <sub>DS</sub> of SR MOSFET.

# **BLOCK DIAGRAM**



#### **ORDERING INFORMATION**

Part Number	Package	Part Marking
SP6019DS8RGB	SOP-8	SP6019D
SP6019DS8TGB	SOP-8	SP6019D

\* SP6019DS8RGB : Tape Reel ; Pb – Free ; Halogen - Free

※ SP6019DS8TGB : Tube ; Pb − Free ; Halogen − Free

#### ABSOULTE MAXIMUM RATINGS (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter	Value	Unit	
V <sub>dd</sub>	DC Supply Voltage	16	V	
$V_{SYNC}/MOSG-C$	Sync/Output Voltage	-0.6~16	V	
V <sub>R/Timing/pred/Adj</sub>	Regulator/ Timing/Pred/Adj Voltage	-0.6~6	V	
ſ	Peak Source Current (Pulsed)	2.0	А	
LOUT	Peak Sink Current (Pulsed)	2.0	А	
P <sub>D</sub>	Power Dissipation @ TA=85°C SOP-8 (*)	0.25	W	
$\Gamma_{J}$	Operating Junction Temperature Range	-40 to125	°C	
T <sub>STG</sub>	Storage Temperature Range	-40 to 150	°C	
T <sub>LEAD</sub>	Lead Soldering Temperature for 5 sec.	260	°C	

#### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit	
Rөjc	Thermal Resistance Junction – Case SOP-8 (*)	45	°C/W	

(\*) The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions.

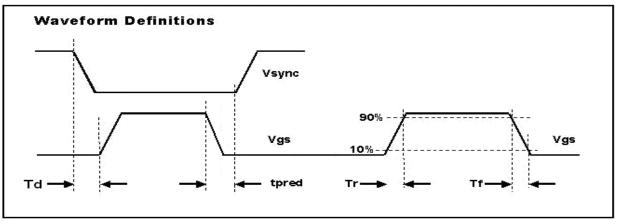


# **ELECTRICAL CHARACTERISTICS**

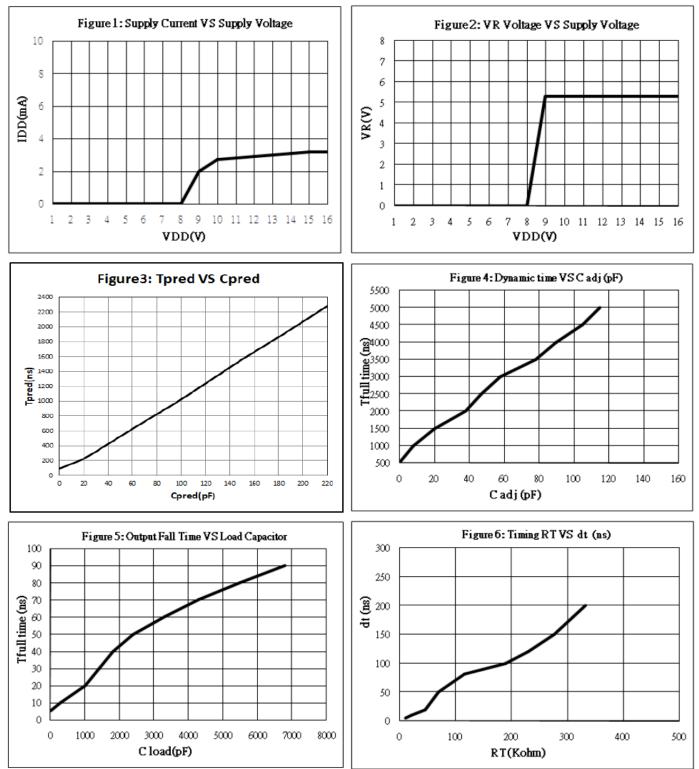
(T<sub>A</sub>=25°C, V<sub>dd</sub>=12V, Freq. =50 KHz, Duty Cycle=50%, unless otherwise specified.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SUPPLY IN	PUT					
Idd	Supply current	No load		0.15		mA
IDD	Suppry current	V <sub>SYNC</sub> =0V, Vdd on		3	4	mA
Vdd	Supply voltage	Idd peak < 2A			16	V
Vdd on	Enable voltage		7.8	8.2	8.6	V
Vdd	Enable voltage			0.25	0.5	V
hysteresis						
Vovp	Over voltage protection		15.5	16.5	17.5	V
Vovp				0.3		v
hystersis				0.5		•
SYNC REFI	ERENCE (SYNC)					
Vshth	SYNC high threshold		3.5	3.9		V
Vslth	SYNC low threshold			0.9	1.2	V
Vsync	SYNC wake-up voltage	Isync=3mA	9		16	V
Isync	SYNC input current				3	mA
Voltage Reg	ulator REFERENCE (VR)					
VR	voltage		5.2		5.4	V
Ivr	VR Output Current				50	mA
ON TIME D	OUTY SETUP (PIN 6)					
Ton-time				26	32	us
MOSFET G	ATE DRIVER (MOSG-C)					
Voh	Output high voltage	Io = -200 mA	10.5	11.0		V
Vol	Output low voltage	Io = 200 mA		0.5	0.8	V
Td	Propagation delay	No load	25	50	155	ns
Tpred		No load		120		ns
Tr	Rise time	Load = 1nF(*)		10	25	ns
Tf	Fall time	Load = 1nF(*)		10	25	ns
Dynamic Pr	otect	· · · · ·	4			
Dt	Dynamic variable	Pin 4 open		600		ns
Ton-min	MOSG-C on time	PWM adjusts time > Dt		0.5		us

(\*) Tr & Tf are measured among 10% and 90% of starting and final voltage.



PERFORMANCE CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified.)



\*Fig. 1 : No Load ; No SYNC

\*Fig. 3 : Frequency = 100 kHz

\*Fig.  $4 \sim 5$  : Frequency = 65 kHz.

\*Fig. 6 : The falling time of negative edge from 3.9V to 0.9V

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